

## FPAM30LH60

### Smart Power Module for 2-phase Interleaved PFC

#### Features

- Single phase rectifier for AC input
- 2-phase interleaved PFC
- Control IC for gate driving and protection
- Built-in NTC thermistor for monitoring over-temperature
- Low thermal resistance due to DBC substrate
- Isolation lating of 2500V<sub>rms</sub>/min
- UL Certified No.E209024

#### Applications

System air conditioner

#### General Description

FPAM30LH60 is an advanced smart power module of 2-phase interleaved PFC(Power Factor Correction). It combines optimized drive circuit with low-loss IGBTs and using DBC which has low thermal resistance. System reliability is further enhanced by the integrated under-voltage lock-out, over-current protection, and built-in NTC thermistor for monitoring over-temperature.

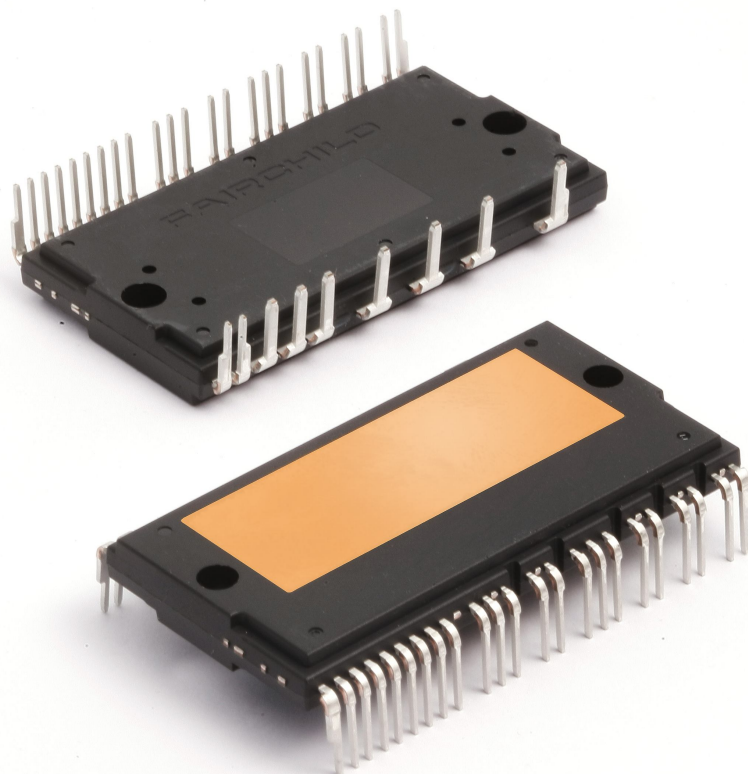
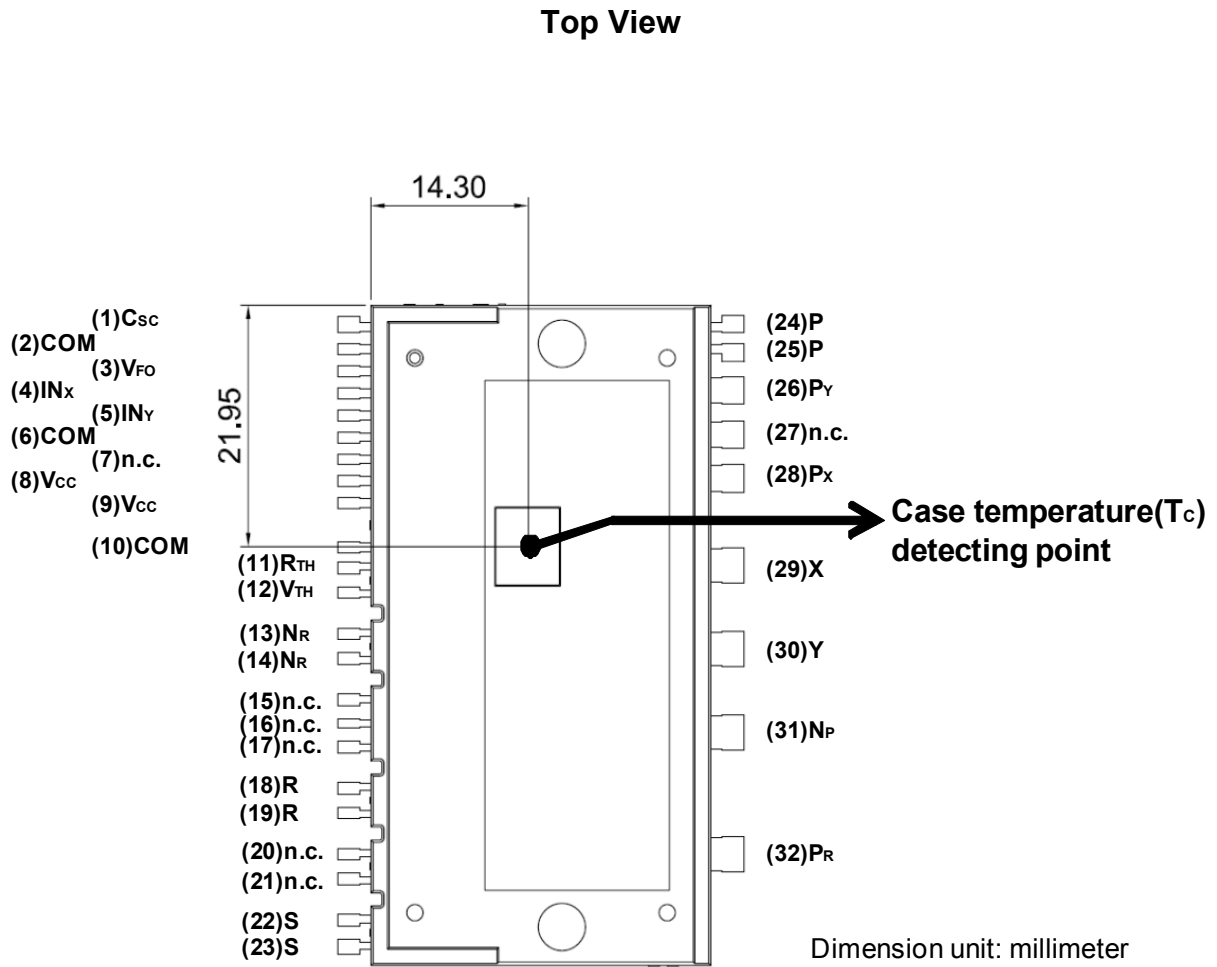


Figure 1.

### Integrated Drive, Protection and System Control Functions

- For IGBTs : Gate drive circuit, Over Current protection(SC), Control supply circuit under-voltage(UV) protection
- Fault signal : Corresponding to SC and UV fault
- Built-in thermistor: Over-temperature monitoring
- Input interface : 3.3/5V CMOS/LSTTL compatible

### Pin Configuration



**Figure 2.**

### Pin Descriptions

Pin Number	Pin Name	Pin Description
1	C <sub>SC</sub>	Signal input for over current detection
2,6,10	COM	Common supply ground
3	V <sub>FO</sub>	Fault out
4	IN <sub>X</sub>	PWM input for X IGBT drive
5	IN <sub>Y</sub>	PWM input for Y IGBT drive
7	n.c.	
8,9	V <sub>CC</sub>	Common supply voltage of IC for IGBT drive
11	R <sub>TH</sub>	Thermister
12	V <sub>TH</sub>	Thermister
13,14	N <sub>R</sub>	Negative DC-link of Rectifier Diode
15,16,17	n.c.	
18,19	R	AC input for R phase
20,21	n.c.	
22,23	S	AC input for S phase
24,25	P	Output of Diode
26	P <sub>Y</sub>	Input of Diode
27	n.c.	
28	P <sub>X</sub>	Input of Diode
29	X	Output of X phase IGBT
30	Y	Output of Y phase IGBT
31	N <sub>P</sub>	Negative DC-link of IGBT
32	P <sub>R</sub>	Positive DC-link of Rectifier Diode

### Internal Equivalent Circuit

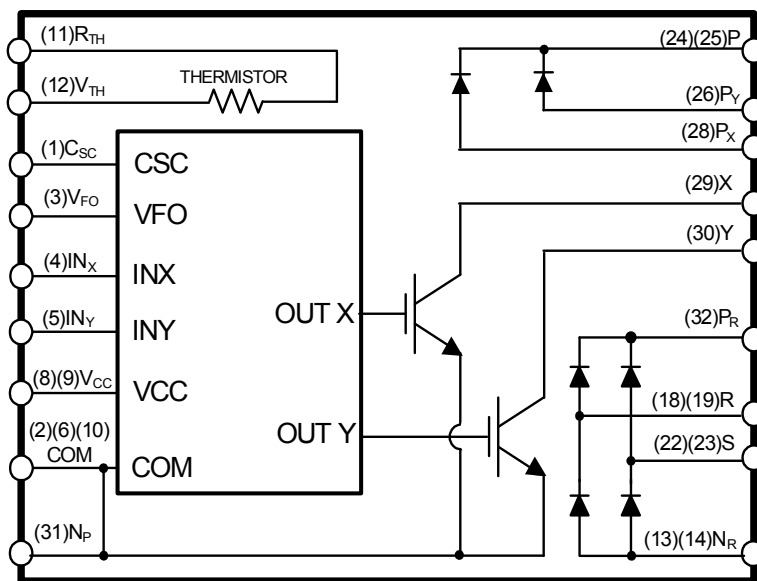


Figure 3. Internal Block Diagram

## Absolute Maximum Ratings (T<sub>J</sub> = 25°C, Unless Otherwise Specified)

### Converter Part

Symbol	Parameter	Conditions	Rating	Units
V <sub>i</sub>	Input Supply Voltage	Applied between R-S	264	V <sub>rms</sub>
V <sub>PN</sub>	Output Voltage	Applied between X-N <sub>P</sub> , Y-N <sub>P</sub> , P-P <sub>X</sub> , P-P <sub>Y</sub>	450	V
V <sub>PN(Surge)</sub>	Output Supply Voltage (Surge)	Applied between X-N <sub>P</sub> , Y-N <sub>P</sub> , P-P <sub>X</sub> , P-P <sub>Y</sub>	500	V
V <sub>CES</sub>	Collector-emitter Voltage	Breakdown Voltage between X-N <sub>P</sub> , Y-N <sub>P</sub>	600	V
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage of FRD	Breakdown Voltage between P-P <sub>X</sub> , P-P <sub>Y</sub>	600	V
V <sub>RRMR</sub>	Repetitive Peak Reverse Voltage of Rectifier	Breakdown Voltage between P <sub>R</sub> -R, P <sub>R</sub> -S, R-N <sub>R</sub> , S-N <sub>R</sub>	900	V
*I <sub>F</sub>	FRD Forward Current	T <sub>C</sub> = 25°C, T <sub>J</sub> < 125°C	30	A
*I <sub>FSM</sub>	Peak Surge Current of FRD	Non-repetitive, 60Hz single half-sine wave	300	A
*I <sub>FR</sub>	Rectified Forward Current	T <sub>C</sub> = 25°C, T <sub>J</sub> < 125°C	30	A
*I <sub>FSMR</sub>	Peak Surge Current of Rectifier	Non-repetitive, 60Hz single half-sine wave	300	A
± *I <sub>IC</sub>	Each IGBT Collector Current	T <sub>C</sub> = 25°C, T <sub>J</sub> < 125°C	30	A
± *I <sub>ICP</sub>	Each IGBT Collector Current(Peak)	T <sub>C</sub> = 25°C, T <sub>J</sub> < 125°C, Under 1ms pulse width	60	A
*P <sub>C</sub>	Collector Dissipation	T <sub>C</sub> = 25°C per single IGBT	107	W
T <sub>J</sub>	Operating Junction Temperature	(Note 1)	-40~125	°C

**Note:**

1. The maximum junction temperature rating of the power chips integrated within the SPM is 125°C.
2. Marking "\*" is calculation value or design factor.

### Control Part

Symbol	Parameter	Conditions	Rating	Units
V <sub>CC</sub>	Control Supply Voltage	Applied between V <sub>CC</sub> - COM	20	V
V <sub>IN</sub>	Input Signal Voltage	Applied between IN <sub>X</sub> , IN <sub>Y</sub> - COM	-0.3 ~ V <sub>CC</sub> +0.3	V
V <sub>FO</sub>	Fault Output Supply Voltage	Applied between V <sub>FO</sub> - COM	-0.3 ~ V <sub>CC</sub> +0.3	V
I <sub>FO</sub>	Fault Output Current	Sink Current at V <sub>FO</sub> Pin	1	mA
V <sub>SC</sub>	Current Sensing Input Voltage	Applied between C <sub>SC</sub> - COM	-0.3 ~ V <sub>CC</sub> +0.3	V

### Total System

Symbol	Parameter	Conditions	Rating	Units
T <sub>STG</sub>	Storage Temperature		-40 ~ 125	°C
V <sub>ISO</sub>	Isolation Voltage	60Hz, Sinusoidal, AC 1 minute, Connection Pins to heat sink plate	2500	V <sub>rms</sub>

### Thermal Resistance

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
R <sub>th(j-c)Q</sub>	Junction to Case Thermal Resistance	Each IGBT under Operating Condition	-	-	0.93	°C/W
R <sub>th(j-c)D</sub>		Each Diode under Operating Condition	-	-	1.42	°C/W
R <sub>th(j-c)R</sub>		Each Rectifier under Operating Condition	-	-	0.74	°C/W

**Electrical Characteristics** ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)**Converter Part**

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
$V_{CE(SAT)}$	IGBT Saturation Voltage	$V_{CC} = 15\text{V}$ , $V_{IN} = 5\text{V}$ , $I_C = 30\text{A}$	-	1.7	2.2	V
$V_{FF}$	FRD Forward Voltage	$I_F = 30\text{A}$	-	1.9	2.4	V
$V_{FR}$	Rectifier Forward Voltage	$I_{FR} = 30\text{A}$	-	1.10	1.25	V
$I_{RR}$	Switching Characteristic	$V_{PN} = 400\text{V}$ , $V_{CC} = 15\text{V}$ , $I_C = 15\text{A}$ , $V_{IN} = 0\text{V} \leftrightarrow 5\text{V}$ , Inductive Load (Note 3), per single IGBT	-	11	-	A
$t_{RR}$			-	41	-	ns
$t_{ON}$			-	700	-	ns
$t_{OFF}$			-	852	-	ns
$t_{C(ON)}$			-	104	-	ns
$t_{C(OFF)}$			-	102	-	ns
$I_{CES}$	Collector-Emitter Leakage Current	$V_{CES} = 600\text{V}$	-	-	250	$\mu\text{A}$

**Note:**

3.  $t_{ON}$  and  $t_{OFF}$  include the propagation delay time of the internal drive IC.  $t_{C(ON)}$  and  $t_{C(OFF)}$  are the switching time of IGBT itself under the given gate driving condition internally. For the detailed information, please see Figure 4.

**Control Part**

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
$I_{QCC}$	Quiescent $V_{CC}$ Supply Current	$V_{CC} = 15\text{V}$ , $IN_X$ , $IN_Y - \text{COM} = 0\text{V}$ , Supply current between $V_{CC}$ and COM	-	-	2.65	mA
$I_{PCC}$	Operating $V_{CC}$ Supply Current	$V_{CC} = 15\text{V}$ , $f_{PWM} = 20\text{kHz}$ , duty=50%, applied to one PWM signal input per single IGBT, Supply current between $V_{CC}$ and COM	-	-	6.0	mA
$V_{FOH}$	Fault Output Voltage	$V_{SC} = 0\text{V}$ , $V_{FO}$ Circuit: 10k $\Omega$ to 5V Pull-up	4.5	-	-	V
$V_{FOL}$		$V_{SC} = 1\text{V}$ , $V_{FO}$ Circuit: 10k $\Omega$ to 5V Pull-up	-	-	0.5	V
$V_{SC(Ref)}$	Over-Current Protection Trip Level Voltage of CSC pin	$V_{CC} = 15\text{V}$	0.45	0.5	0.55	V
$UV_{CCD}$	Supply Circuit Under-Voltage Protection	Detection Level	10.5	-	13.0	V
$UV_{CCR}$		Reset Level	11.0	-	13.5	V
$t_{FOD}$	Fault-out Pulse Width		30	-	-	$\mu\text{s}$
$V_{IN(ON)}$	ON Threshold Voltage	Applied between $IN_X$ , $IN_Y - \text{COM}$	2.6	-	-	V
$V_{IN(OFF)}$	OFF Threshold Voltage	Applied between $IN_X$ , $IN_Y - \text{COM}$	-	-	0.8	V
$R_{TH}$	Resistance of Thermistor	@ $T_{TH} = 25^\circ\text{C}$ (Figure 5)(Note 4)	-	47	-	k $\Omega$
		@ $T_{TH} = 100^\circ\text{C}$ (Figure 5)(Note 4)	-	2.9	-	k $\Omega$

**Note:**

4.  $T_{TH}$  is the temperature of thermistor itself. To know case temperature ( $T_C$ ), please make the experiment considering your application.

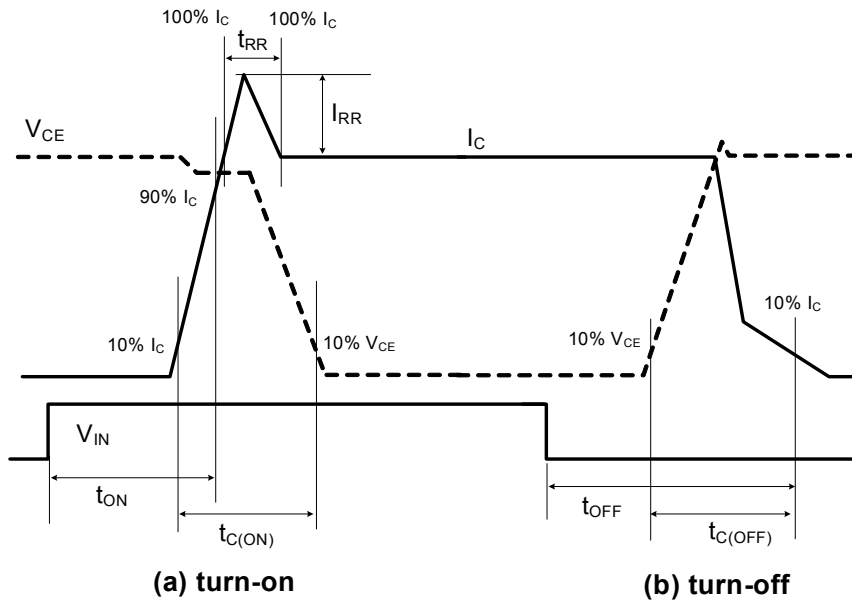


Figure 4. Switching Time Definition

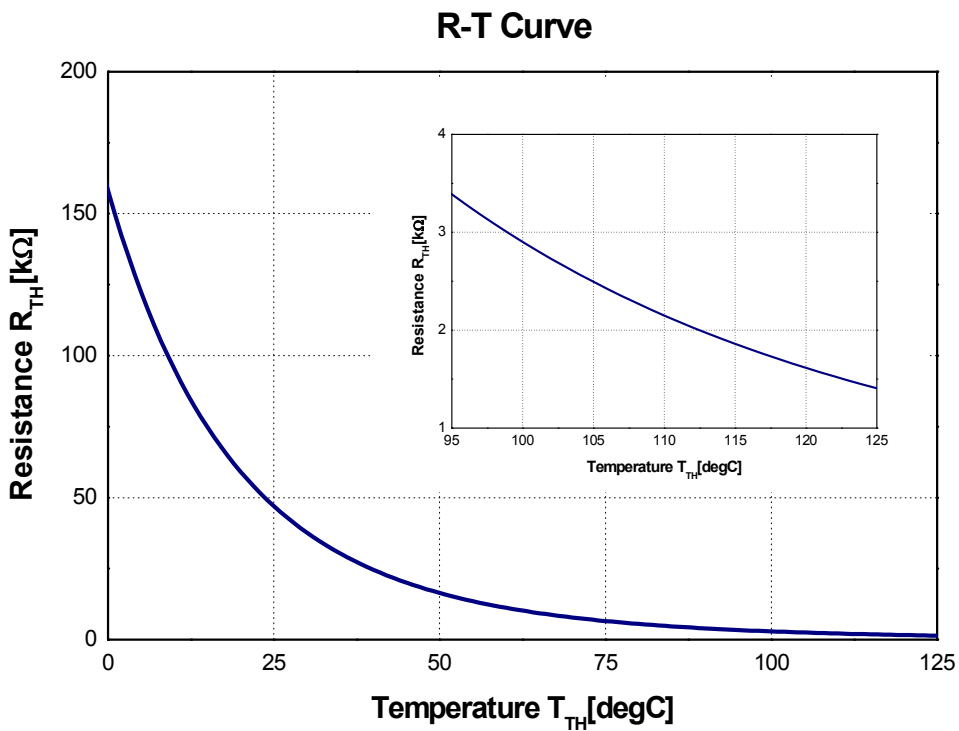


Figure 5. R-T Curve of The Built-in Thermistor

**Recommended Operating Conditions** ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)

Symbol	Parameter	Conditions	Value			Units
			Min.	Typ.	Max.	
$V_i$	Input Supply Voltage	Applied between R - S	187	-	253	$V_{rms}$
$I_i$	Input Current	$T_C < 100^\circ\text{C}$ , $V_i = 220\text{V}$ , $V_O = 360\text{V}$ , $f_{PWM} = 20\text{kHz}$ per each IGBT	-	-	21	$A_{rms}$
$V_{PN}$	Supply Voltage	Applied between X- $N_P$ , Y- $N_P$ , P- $P_X$ , P- $P_Y$	-	-	400	V
$V_{CC}$	Control Supply Voltage	Applied between $V_{CC}$ - COM	13.5	15	16.5	V
$dV_{CC}/dt$	Supply Variation		-1	-	1	$V/\mu\text{s}$
$I_{FO}$	Fault Output Current	Sink Current at $V_{FO}$ Pin	-	-	1	mA
$f_{PWM}$	PWM Input Frequency	$-40^\circ\text{C} < T_J < 125^\circ\text{C}$ per single IGBT	-	20	-	kHz

**Mechanical Characteristics and Ratings**

Parameter	Conditions		Limits			Units
			Min.	Typ.	Max.	
Mounting Torque	Mounting Screw: M4	Recommended 0.98N•m	0.78	0.98	1.17	N•m
		Recommended 10kg•cm	8	10	12	kg•cm
Device Flatness	Refer to Figure 6		0	-	+150	$\mu\text{m}$
Weight			-	32	-	g

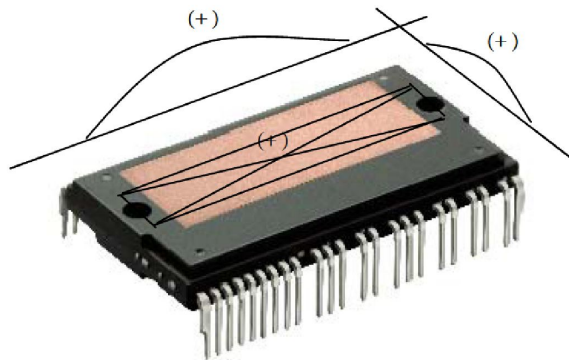
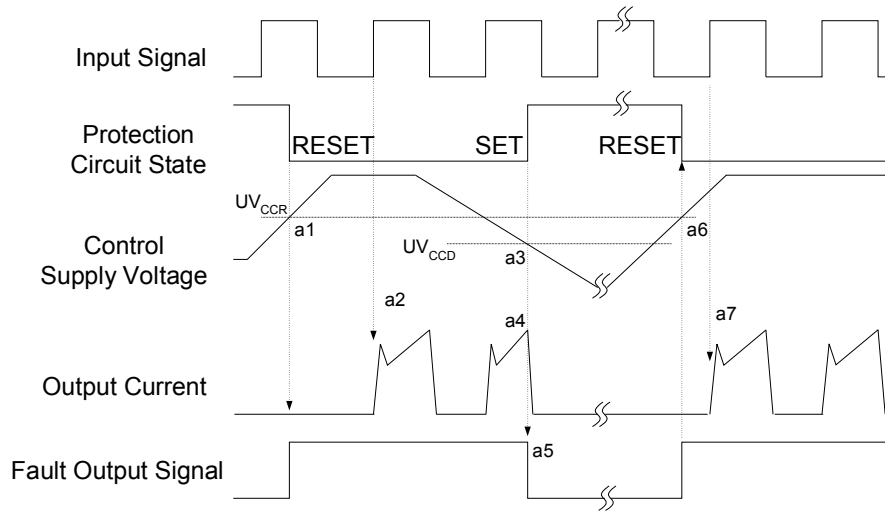


Figure 6. Flatness Measurement Position

**Package Marking and Ordering Information**

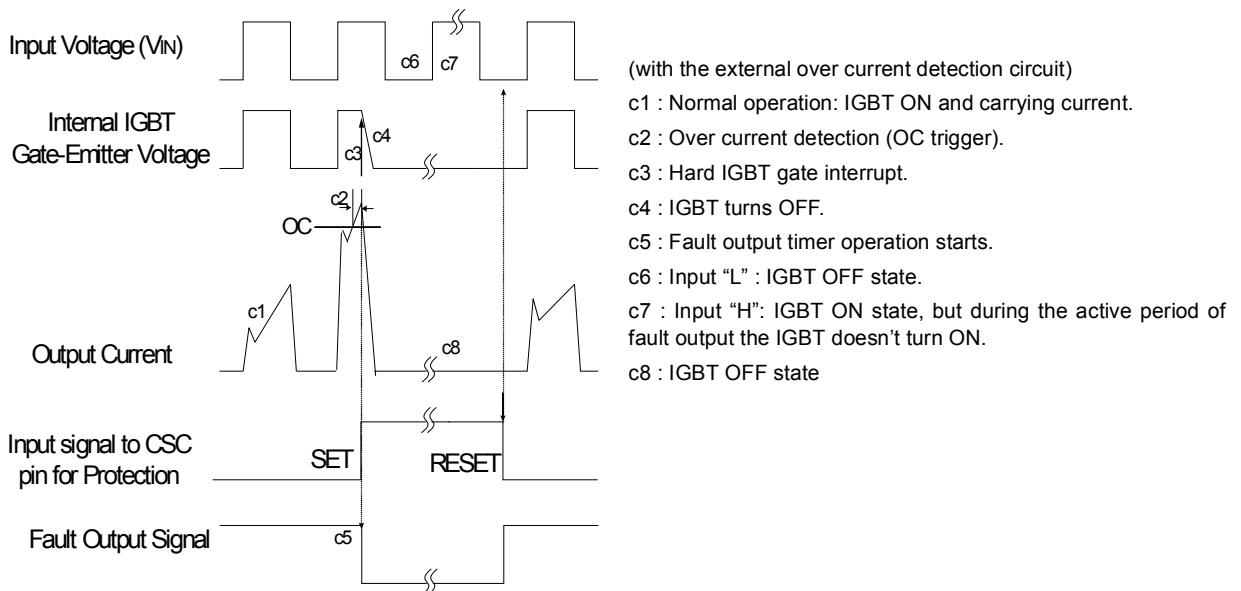
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FPAM30LH60	FPAM30LH60	SPM32-EA	-	-	8

### Time Charts of Protective Function



- a1 : Control supply voltage rises: After the voltage rises  $UV_{CCR}$ , the circuits start to operate when the next input is applied.
- a2 : Normal operation: IGBT ON and carrying current.
- a3 : Under voltage detection ( $UV_{CCD}$ ).
- a4 : IGBT OFF in spite of control input condition.
- a5 : Fault output operation starts.
- a6 : Under voltage reset ( $UV_{CCR}$ ).
- a7 : Normal operation: IGBT ON and carrying current.

**Figure 7. Under-Voltage Protection**

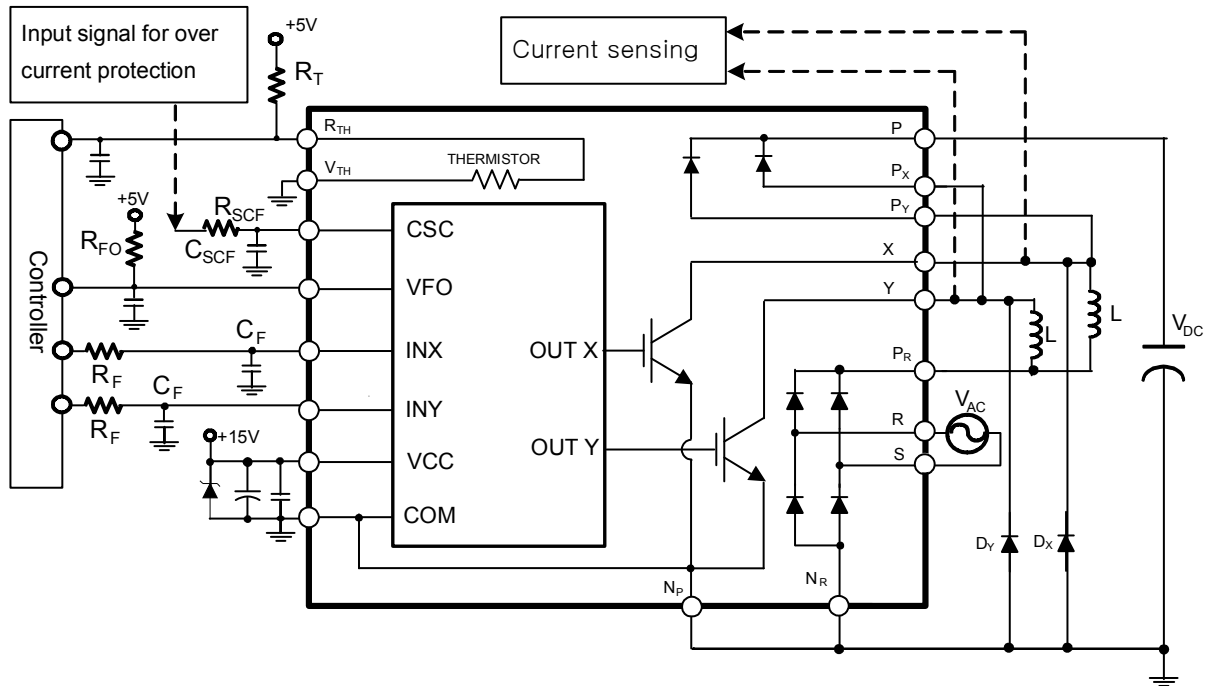


(with the external over current detection circuit)

- c1 : Normal operation: IGBT ON and carrying current.
- c2 : Over current detection (OC trigger).
- c3 : Hard IGBT gate interrupt.
- c4 : IGBT turns OFF.
- c5 : Fault output timer operation starts.
- c6 : Input "L" : IGBT OFF state.
- c7 : Input "H" : IGBT ON state, but during the active period of fault output the IGBT doesn't turn ON.
- c8 : IGBT OFF state

**Figure 8. Over Current Protection**



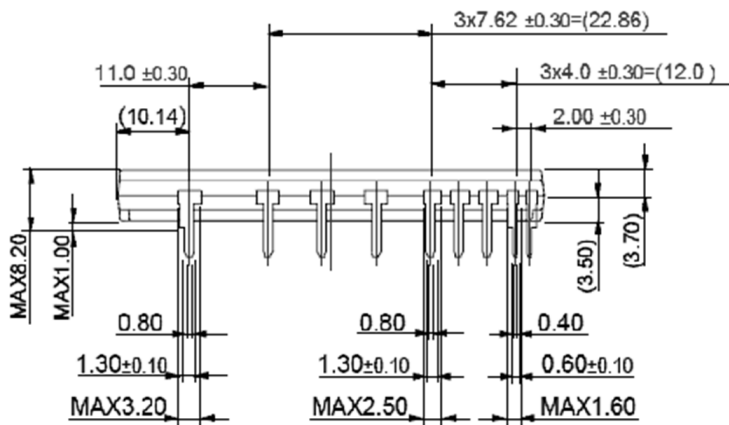
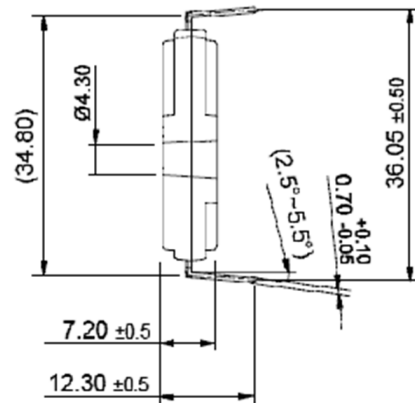
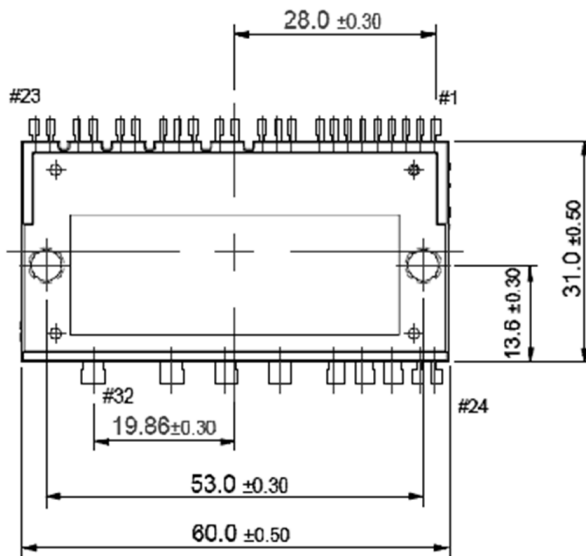
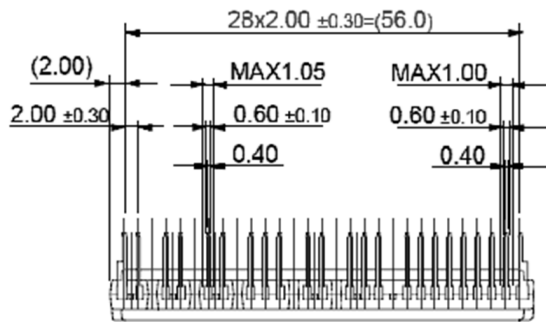


**Note:**

1. To avoid malfunction, the wiring of each input should be as short as possible. (less than 2~3cm)
2. V<sub>FO</sub> output is open drain type. This signal line should be pulled up to the positive side of the MCU or control power supply with a resistor that makes I<sub>FO</sub> up to 1mA.
3. Input signal is High-Active type. There is a 5kΩ resistor inside the IC to pull down each input signal line to GND. RC coupling circuits is recommended for the prevention of input signal oscillation. R<sub>F</sub>C<sub>F</sub> constant should be selected in the range 50~150ns. (Recommended R<sub>F</sub>=100Ω, C<sub>F</sub>=1nF)
4. To prevent error of the protection function, the wiring related with R<sub>SCF</sub> and C<sub>SCF</sub> should be as short as possible.
5. In the over current protection circuit, please select the R<sub>SCF</sub>, C<sub>SCF</sub> time constant in the range 1.5~2 μs.
6. Each capacitors should be mounted as close to the SPM pins as possible.
7. Relays are used at almost every systems of electrical equipments of home appliances. In these cases, there should be sufficient distance between the CPU and the relays.
8. Internal NTC thermistor can be used for monitoring of the case temperature and protecting the device from the overheating operation. Select an appropriate resistor R<sub>T</sub> according to the application.
9. It is recommended that anti-parallel diode(D<sub>X</sub>, D<sub>Y</sub>) be connected with each IGBT.

**Figure 9. Typical Application Circuit**

Detailed Package Outline Drawings







Dimension unit: millimeter



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